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                 Web Page for STN Seminar Schedule - N. America
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         JAN 02
                 STN pricing information for 2008 now available
                CAS patent coverage enhanced to include exemplified
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        JAN 16
                 prophetic substances
        JAN 28
NEWS
                USPATFULL, USPAT2, and USPATOLD enhanced with new
                 custom IPC display formats
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      5
        JAN 28
                MARPAT searching enhanced
NEWS
     6 JAN 28
                USGENE now provides USPTO sequence data within 3 days
                 of publication
        JAN 28 TOXCENTER enhanced with reloaded MEDLINE segment
NEWS
     7
        JAN 28 MEDLINE and LMEDLINE reloaded with enhancements
NEWS 8
NEWS 9 FEB 08
                STN Express, Version 8.3, now available
NEWS 10 FEB 20 PCI now available as a replacement to DPCI
NEWS 11 FEB 25
                IFIREF reloaded with enhancements
NEWS 12 FEB 25
                IMSPRODUCT reloaded with enhancements
NEWS 13 FEB 29 WPINDEX/WPIDS/WPIX enhanced with ECLA and current
                 U.S. National Patent Classification
NEWS 14 MAR 31
                IFICDB, IFIPAT, and IFIUDB enhanced with new custom
                 IPC display formats
NEWS 15 MAR 31
                CAS REGISTRY enhanced with additional experimental
                 spectra
NEWS 16 MAR 31
                CA/CAplus and CASREACT patent number format for U.S.
                 applications updated
NEWS 17
        MAR 31
                LPCI now available as a replacement to LDPCI
NEWS 18 MAR 31
                EMBASE, EMBAL, and LEMBASE reloaded with enhancements
NEWS 19
                STN AnaVist, Version 1, to be discontinued
        APR 04
NEWS 20 APR 15
                WPIDS, WPINDEX, and WPIX enhanced with new
                 predefined hit display formats
NEWS 21 APR 28
                EMBASE Controlled Term thesaurus enhanced
NEWS 22 APR 28
                IMSRESEARCH reloaded with enhancements
                INPAFAMDB now available on STN for patent family
NEWS 23 MAY 30
                 searching
NEWS 24 MAY 30
                DGENE, PCTGEN, and USGENE enhanced with new homology
                 sequence search option
NEWS 25
         JUN 06 EPFULL enhanced with 260,000 English abstracts
        JUN 06 KOREAPAT updated with 41,000 documents
NEWS EXPRESS FEBRUARY 08 CURRENT WINDOWS VERSION IS V8.3,
             AND CURRENT DISCOVER FILE IS DATED 20 FEBRUARY 2008
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              Welcome Banner and News Items
NEWS IPC8
              For general information regarding STN implementation of IPC 8
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=> FILE REG

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SINCE FILE TOTAL ENTRY SESSION 0.42 0.42

FULL ESTIMATED COST

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STRUCTURE FILE UPDATES: 9 JUN 2008 HIGHEST RN 1026855-74-2 DICTIONARY FILE UPDATES: 9 JUN 2008 HIGHEST RN 1026855-74-2

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1 2 3 4 5 6 7 8 9 10 11 12 13 14

ring bonds :

1-2 1-6 2-3 3-4 4-5 5-6 5-7 6-10 7-8 8-9 8-11 9-10 9-14 11-12 12-13 13-14

normalized bonds :

Match level:

1:Atom 2:Atom 3:Atom 4:Atom 5:Atom 6:Atom 7:Atom 8:Atom 9:Atom 10:Atom 11:Atom 12:Atom 13:Atom 14:Atom

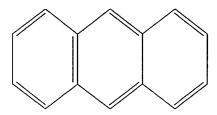
L1 STRUCTURE UPLOADED

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L1 HAS NO ANSWERS

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Structure attributes must be viewed using STN Express query preparation.

=> S L1 FULL

FULL SEARCH INITIATED 17:25:50 FILE 'REGISTRY'
FULL SCREEN SEARCH COMPLETED - 486996 TO ITERATE

100.0% PROCESSED 486996 ITERATIONS

79682 ANSWERS

SEARCH TIME: 00.00.08

L2 79682 SEA SSS FUL L1

=> FILE CAPLUS

COST IN U.S. DOLLARS

SINCE FILE TOTAL ENTRY SESSION 178.82 179.24

FULL ESTIMATED COST

FILE 'CAPLUS' ENTERED AT 17:26:08 ON 10 JUN 2008 USE IS SUBJECT TO THE TERMS OF YOUR STN CUSTOMER AGREEMENT. PLEASE SEE "HELP USAGETERMS" FOR DETAILS. COPYRIGHT (C) 2008 AMERICAN CHEMICAL SOCIETY (ACS)

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FILE COVERS 1907 - 10 Jun 2008 VOL 148 ISS 24 FILE LAST UPDATED: 9 Jun 2008 (20080609/ED)

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=> S L2

L3 101687 L2

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=> S L3 AND SEMICONDUCTOR

642362 SEMICONDUCTOR

L4 2088 L3 AND SEMICONDUCTOR

=> S L4 AND BINDER

195554 BINDER

L5 26 L4 AND BINDER

=> D L5 · IBIB ABS HITSTR 1-26

L5 ANSWER 1 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER:

2008:315927 CAPLUS

DOCUMENT NUMBER:

148:318707

TITLE:

Laser-decomposing resin compositions having high sensitivity and good pattern profiles and their

pattern-forming materials

INVENTOR(S):

Taguchi, Takanori

PATENT ASSIGNEE(S):

Fuji Photo Film Co., Ltd., Japan Jpn. Kokai Tokkyo Koho, 53pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

SOURCE:

Japanese

FAMILY ACC. NUM. COUNT:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
			,	
JP 2008056888 PRIORITY APPLN. INFO.:	Α	20080313	JP 2007-42844 JP 2006-208397	20070222
GI			01 2000 20003, 1	20000731

AB The resin compns. contain dienophile compds. and diene compds., and/or adducts of dienophile compds. and diene compds. Preferably, the dienophile compds. comprise I and the diene compds. comprise II (X1-X4, Y1-Y6 = H, monovalent substituent, polyvalent nonmetallic atom. group; X1 and X2, X3 and X4, Y1 and Y3, or Y2 and Y4 may be bonded together and form ring structure). Preferably, the adducts of the dienophile compds. and the diene compds. comprise III (X1-X4, Y1-Y6 = same as above). Laser-decomposing resin compns. containing Diels-Alder reaction products of dienophile compds. and diene compds., preferably, represented by I and II resp. Preferably, the laser-decomposing resin compns. further contain binder polymers and polymerizable compds. The pattern-forming materials comprise substrates having thereon layers of the laser-decomposing resin compns. The patterns are formed by irradiating CO2 laser, semiconductor laser, YAG laser, or fiber laser. The pattern-forming materials may be laser-sensitive flexog. printing original plates.

IT 1009623-61-3

RL: MOA (Modifier or additive use); RCT (Reactant); RACT (Reactant or reagent); USES (Uses)

(laser-decomposing resin compns. having high sensitivity and good pattern profiles and their pattern-forming materials for flexog. printing plates)

RN 1009623-61-3 CAPLUS

CN Carbamic acid, N,N'-(methylenedi-4,1-phenylene)bis-, C,C'-bis(9-anthracenylmethyl) ester (CA INDEX NAME)

L5 ANSWER 2 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER: 2008:121202 CAPLUS

DOCUMENT NUMBER: 148:201707

TITLE: Organic light-emitting material formulation including

a luminescent material housed in a protective porous

matrix material mixed with a binder and a

solvent

INVENTOR(S): Brunacci, Antonio; Jouanique-Dubuis, Cecile

PATENT ASSIGNEE(S): Iee International Electronics & Engineering S.A.,

Luxembourg

SOURCE: Eur. Pat. Appl., 10pp.

CODEN: EPXXDW

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT N	0.		KIN	D	DATE		1	APPL:	ICAT:	ION 1	10.		D	ATE	
				_			•								
EP 18831	24		A 1		2008	0130	1	EP 2	006-1	1179	71		2	0060	727
R:	AT, BE,	BG,	CH,	CY,	CZ,	DE,	DK,	EE,	ES,	FI,	FR,	GB,	GR,	HU,	IE,
	IS, IT,	LI,	LT,	LU,	LV,	MC,	NL,	PL,	PT,	RO,	SE,	SI,	SK,	TR,	AL,
	BA, HR,	MK,	YU					•							

PRIORITY APPLN. INFO.:

EP 2006-117971 20060727

AB A formulation of light-emitting material particularly suitable for forming displays and lamps via printing techniques comprises organic light emitting material housed in protective porous matrix material; a binder; and a solvent. The matrix material is selected from microporous and mesoporous materials, such as zeolites, porous oxides, mol. sieves, silicoaluminophosphates and aluminosilicates. Method of manufacturing electroluminescent devices employing the luminescent formulation are also discussed.

IT 62555-84-4

RL: PEP (Physical, engineering or chemical process); TEM (Technical or engineered material use); PROC (Process); USES (Uses)

(light-emitting material; organic light-emitting material formulation including a luminescent material housed in protective porous matrix material mixed with binder and solvent)

RN 62555-84-4 CAPLUS

CN 9H-Carbazole, 3,3'-(9,10-anthracenediyldi-2,1-ethenediyl)bis[9-ethyl- (CA INDEX NAME)

PAGE 2-A

REFERENCE COUNT:

THERE ARE 5 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L5 ANSWER 3 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

5

ACCESSION NUMBER:

2007:816621 CAPLUS

DOCUMENT NUMBER:

147:224628

TITLE:

Electronic short channel device comprising an organic

semiconductor formulation

INVENTOR(S):

Ogier, Simon Dominic; Veres, Janos; Zeidan, Munther

Merck Patent G.m.b.H., Germany

PATENT ASSIGNEE(S):

PCT Int. Appl., 46pp.

SOURCE:

CODEN: PIXXD2

DOCUMENT TYPE:

Patent

LANGUAGE:

English

FAMILY ACC. NUM. COUNT:

PAT	ENT	NO.			KIN	D	DATE		i	APPL:	ICAT:	ION 1	NO.		D	ATE	
WO	2007	0825	84		A1	_	2007	0726		WO 2	006-1	EP12:	 300		20	0061	220
		AE,															
		CN,	co,	CR,	CU,	CZ,	DE,	DK,	DM,	DZ,	EC,	EE,	EG,	ES,	FI,	GB,	GD,
		GE,	GH,	GM,	GT,	HN,	HR,	HU,	ID,	IL,	IN,	IS,	JP,	KE,	KG,	KM,	KN,

KP, KR, KZ, LA, LC, LK, LR, LS, LT, LU, LV, LY, MA, MD, MG, MK, MN, MW, MX, MY, MZ, NA, NG, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RS, RU, SC, SD, SE, SG, SK, SL, SM, SV, SY, TJ, TM, TN, TR, TT,

TZ, UA, UG, US, UZ, VC, VN, ZA, ZM, ZW

RW: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LT, LU, LV, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG, BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM

PRIORITY APPLN. INFO.:

EP 2006-1282 A 20060121

AB The invention relates to an improved electronic device, like an organic field emission transistor (OFET), which has a short source to drain channel length and contains an organic semiconducting formulation comprising a semiconducting binder.

IT 373596-08-8

RL: PRP (Properties); TEM (Technical or engineered material use); USES (Uses)

(electronic short channel device comprising an organic semiconductor formulation in organic field emission transistors)

RN 373596-08-8 CAPLUS

CN Pentacene, 6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)

REFERENCE COUNT: 6 THERE ARE 6 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L5 ANSWER 4 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER: 2006:1339367 CAPLUS

DOCUMENT NUMBER:

146:91393

TITLE:

Method of patterning nano conductive film

INVENTOR(S):

Park, Jong-Jin; Kim, Myeong-Suk; Noh, Tae-Yong; Lee,

Sung-Hun; Lee, Sang-Yoon; Jeong, Eun-Jeong

PATENT ASSIGNEE(S):

S. Korea

SOURCE:

U.S. Pat. Appl. Publ., 11pp.

CODEN: USXXCO

DOCUMENT TYPE:

Patent

LANGUAGE:

English

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
US 20060284169	A1	20061221	US 2006-394085	20060331
KR 2006132396	Α	20061221	KR 2005-52721	20050618
CN 1881642	A ·	20061220	CN 2006-10073281	20060407
JP 2006351543	Α	20061228	JP 2006-167517	20060616
PRIORITY APPLN. INFO.:			KR 2005-52721 A	20050618
OTHER SOURCE(S):	MARPAT	146:91393		

AB A donor substrate for forming a nano conductive film includes a base substrate and a transferring layer that is disposed on the base substrate. The transferring layer includes nano conductive particles and an organic semiconductor. A method of patterning a nano conductive film is provided, wherein a donor substrate in which nano conductive particles are

dispersed by employing an organic semiconductor having low mol. weight as a binder was prepared, and nano conductive particles are patterned on a receptor substrate by employing the donor substrate. The method can be used to prepare patterns of various devices including a display device such as an OLED and an OTFT. Such a device can be prepared simply and economically by preparing a device comprising nano conductive particles and an organic semiconductor in wet basis even without deposition.

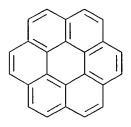
IT 92-24-0D, Tetracene, derivs. 120-12-7D, Anthracene,
 derivs. 135-48-8D, Pentacene, derivs. 191-07-1,
 Coronene 191-07-1D, Coronene, derivs. 517-51-1,
 Rubrene 517-51-1D, Rubrene, derivs.
 RL: PEP (Physical, engineering or chemical process); TEM (Technical or
 engineered material use); PROC (Process); USES (Uses)
 (method of patterning nano conductive film for semiconductor
 devices)

RN 92-24-0 CAPLUS CN Naphthacene (CA INDEX NAME)

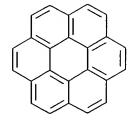
RN 120-12-7 CAPLUS
CN Anthracene (CA INDEX NAME)

RN 135-48-8 CAPLUS CN Pentacene (CA INDEX NAME)

RN 191-07-1 CAPLUS CN Coronene (CA INDEX NAME)



RN 191-07-1 CAPLUS CN Coronene (CA INDEX NAME)



RN 517-51-1 CAPLUS

CN Naphthacene, 5,6,11,12-tetraphenyl- (CA INDEX NAME)

RN 517-51-1 CAPLUS

CN Naphthacene, 5,6,11,12-tetraphenyl- (CA INDEX NAME)

L5 ANSWER 5 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER: 2006:437554 CAPLUS

DOCUMENT NUMBER: 144:479184

TITLE: Process for making an organic field effect transistor

with areas of reduced carrier mobility

INVENTOR(S): Brown, Beverley Anne; Veres, Janos; Ogier, Simon

Dominic

PATENT ASSIGNEE(S): Merck Patent G.m.b.H., Germany

SOURCE: PCT Int. Appl., 24 pp.

CODEN: PIXXD2

DOCUMENT TYPE: Patent

LANGUAGE: English

FAMILY ACC. NUM. COUNT: PATENT INFORMATION:

PA	PENT	NO.			KIN	D	DATE			APPL	ICAT	ION 1	.00		. D.	ATE	
WO	2006	0480	92		A1	-	2006	0511	1	WO 2	 005-:	EP10	 661		2	0051	004
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		CN,	CO,	CR,	CU,	CZ,	DE,	DK,	DM,	DZ,	EC,	EE,	EG,	ES,	FI,	GB,	GD,
		GE,	GH,	GM,	HR,	HU,	ID,	IL,	IN,	IS,	JP,	KE,	KG,	KM,	KP,	KR,	ΚZ,
		LC,	LK,	LR,	LS,	LT,	LU,	LV,	LY,	MA,	MD,	MG,	MK,	MN,	MW,	MX,	MZ,
		NA.	NG.	NT.	NO.	NZ.	OM.	PG.	PH.	PI.	PT.	RO.	RII.	SC.	SD.	SE.	SG.

SK, SL, SM, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW RW: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LT, LU, LV, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG, BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM 20070718 EP 2005-790320 A1 AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LI, LT, LU, LV, MC, NL, PL, PT, RO, SE, SI, SK, TR JP 2008519445 Т 20080605 JP 2007-539481 20051004 KR 2007083921 Α 20070824 KR 2007-710026 20070502 US 20070259477 20071108 **A**1 US 2007-666751 20070502 PRIORITY APPLN. INFO.: GB 2004-24342 20041103 WO 2005-EP10661 W 20051004

AB The present invention relates to a process for reducing the mobility of an organic semiconductor (OSC) layer in an electronic device having a semiconducting channel area. The mobility of the OSC is reduced in specific areas outside the channel area by applying an oxidizing agent to the OSC layer.

IT 373596-08-8

RL: DEV (Device component use); USES (Uses)

(organic semiconductor layer; process for making an organic field effect transistor with areas of reduced carrier mobility)

RN 373596-08-8 CAPLUS

CN Pentacene, 6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)

REFERENCE COUNT: 4 THERE ARE 4 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L5 ANSWER 6 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER: 2006:49396 CAPLUS

DOCUMENT NUMBER: 144:140478

TITLE: Method for fabricating semiconductor element

from dispersion of semiconductor particles

INVENTOR(S): Kugler, Thomas; Newsome, Christopher; Russel, David;

Li, Shunpu

PATENT ASSIGNEE(S): Seiko Epson Corporation, Japan

SOURCE: U.S. Pat. Appl. Publ., 10 pp.

CODEN: USXXCO

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
US 20060014365	A 1	20060119	US 2005-125138	20050510
GB 2416428	Α	20060125	GB 2004-16124	20040719
KR 2006046268	Α	20060517	KR 2005-45497	20050530
JP 2006041495	Α	20060209	JP 2005-180203	20050621
CN 1725455	Α	20060125	CN 2005-10083398	20050718

PRIORITY APPLN. INFO.:

GB 2004-16124

A 20040719

Provided is a method for forming a semiconductor element such as film. The method comprises the steps of: (i) depositing a suspension of particles of a first semiconductor and a solution of a second semiconductor or a precursor thereof on a surface of a substrate such that a mixture comprising the particles of the first semiconductor suspended in a liquid phase comprising the second semiconductor or precursor thereof results thereon; and (ii) solidifying the mixture to form the semiconductor element comprising particles of the first semiconductor in a matrix of the second semiconductor which elec. connects adjacent particles of the first semiconductor, the first and second semiconductors being of the same conductivity type and being formed from either the same or different materials. The method does not require any step of vacuum deposition or sintering. Also provided is a semiconductor element itself. The element comprises semiconductor particles in a matrix of a semiconductor binder that has the same conductivity type as the semiconductor particles and which is the same or a different material than that forming the particles, the semiconductor binder elec. connecting adjacent semiconductor particles. The above stated semiconductor film is formed in fabrication of thin-film transistor, organic light-emitting element, etc.

IT 135-48-8, Pentacene 1065-80-1, Hexabenzocoronene RL: DEV (Device component use); PRP (Properties); USES (Uses) (fabricating of semiconductor element from dispersion of semiconductor particles)

RN 135-48-8 CAPLUS

Pentacene (CA INDEX NAME) CN

RN 1065-80-1 CAPLUS

CN Hexabenzo[a,d,g,j,m,p]coronene (CA INDEX NAME)

ANSWER 7 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER: 2005:1005014 CAPLUS

DOCUMENT NUMBER:

143:317185

TITLE:

Solid electrolytic capacitor and the use thereof

INVENTOR(S): Naito, Kazumi; Tamura, Katutoshi

PATENT ASSIGNEE(S):

Showa Denko K.K., Japan PCT Int. Appl., 35 pp.

SOURCE:

CODEN: PIXXD2

DOCUMENT TYPE:

Patent English

LANGUAGE: FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

	PATENT NO.					KIND DATE			APPLICATION NO.						DATE			
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									DK,									
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									MD,							-	-	-
			NZ,	OM,	PG,	PH,	PL,	PT.	RO,	RU.	SC,	SD,	SE,	SG,	SK.	SL.	SM.	SY.
			ΤJ,	TM,	TN,	TR,	TT,	TZ,	UA,	UG,	US,	UZ,	VC,	VN,	YU,	ZA,	ZM.	ZW
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	CN	1930	647			Α		2007	0314	(CN 2	005-	8000	7507		2	0050	308
	US	2007	0206	344		A1		2007	0906	1	US 2	006-	5923	77		2	0060	911
PRIO	RIT	APP	LN.	INFO	. :						JP 2	004-	6507	2		A 2	0040	309
										1	US ·2	004-	5535	29P		P 2	0040	317
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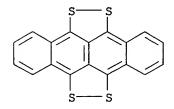
AB The present invention relates to a solid electrolytic capacitor with low ESR obtained by stacking a dielec. layer on a surface of an anode body comprising a valve-acting metal or an elec. conducting oxide, further sequentially stacking a semiconductor layer and an elec. conducting layer on the dielec. layer to prepare a solid electrolytic capacitor element, and molding it with a jacket material, the elec. conducting layer having an elec. conducting paste layer mainly comprising an elec. conducting metal powder and resin, wherein the tap d. of the elec. conducting metal powder is 4 g/cm3 or more, and an electronic circuit and an electronic device using the solid electrolytic capacitor. \mathbf{IT} 193-44-2, Tetrathiotetracene

RL: PEP (Physical, engineering or chemical process); PYP (Physical process); TEM (Technical or engineered material use); PROC (Process); USES (Uses)

(fabrication of solid electrolytic capacitor with low equivalent series resistance)

RN 193-44-2 CAPLUS

CN Naphthaceno[5,6-cd:11,12-c'd']bis[1,2]dithiole (CA INDEX NAME)



REFERENCE COUNT:

THERE ARE 4 CITED REFERENCES AVAILABLE FOR THIS 4 RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

ANSWER 8 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER:

2005:523782 CAPLUS

DOCUMENT NUMBER:

143:69829

TITLE:

Improvements in and relating to organic semiconducting

layers

INVENTOR(S):

Brown, Beverley Anne; Veres, Janos; Anemian, Remi

Manouk; Williams, Richard Thomas; Ogier, Simon

Dominic; Leeming, Stephen William

PATENT ASSIGNEE(S):

Avecia Limited, UK PCT Int. Appl., 68 pp.

CODEN: PIXXD2

DOCUMENT TYPE:

SOURCE:

Patent English

LANGUAGE: EXEMPLY ACC. NUM. COUNT: 1

PATENT INFORMATION:

P					KIND DATE			APPLICATION NO.						DATE			
	0 2005				A2		2005	0616			004-	GB49	73		2	0041	125
W	0 2005	0552	48		A3		2005	0728									
	W:	ΑE,	ΑG,	AL,	AM,	AT,	AU,	ΑZ,	BA,	BB,	BG,	BR,	BW,	BY,	BZ,	CA,	CH,
		CN,	CO,	CR,	CU,	CZ,	DE,	DK,	DM,	DZ,	EC,	EE,	EG,	ES,	FI,	GB,	GD,
		GE,	GH,	GM,	HR,	HU,	ID,	IL,	IN,	IS,	JP,	ΚĖ,	KG,	KP,	KR,	KZ,	LC,
		LK,	LR,	LS,	LT,	LU,	LV,	MA,	MD,	MG,	MK,	MN,	MW,	MX,	MZ,	NA,	NI,
		NO,	NZ,	OM,	PG,	PH,	PL,	PT,	RO,	RU,	SC,	SD,	SE,	SG,	SK,	SL,	SY,
		ТJ,	TM,	TN,	TR,	TT,	TZ,	UA,	UG,	US,	UZ,	VC,	VN,	YU,	ZA,	ZM,	ZW
	RW:	BW,	GH,	GM,	KE,	LS,	MW,	MZ,	NA,	SD,	SL,	SZ,	TZ,	UG,	ZM,	ZW,	AM,
		ΑŻ,	BY,	KG,	KZ,	MD,	RU,	ТJ,	TM,	ΑT,	BE,	BG,	CH,	CY,	CZ,	DE,	DK,
		EE,	ES,	FI,	FR,	GB,	GR,	HU,	ΙE,	IS,	IT,	LU;	MC,	NL,	PL,	PT,	RO,
		SE,	SI,	SK,	TR,	BF,	ВJ,	CF,	CG,	CI,	CM,	GΑ,	GN,	GQ,	GW,	ML,	MR,
		NE,	SN,	TD,	TG												
E	P 1687						2006									0041	
	R:	AT,													SE,	MC,	PT,
		ΙE,	SI,	FI,	RO,	CY,	TR,	BG,	CZ,	EE,	HU,	PL,	SK,	IS			
E	P 1783	3781			A2		2007	0509		EP 2	007-	2498			2	0041	125
E	P 1783						2007	1003									
	R:						CZ,								GR,	HU,	IE,
		IS,	IT,	LI,	LU,	MC,	NL,										
J	P 2007			•			2007									0041	125
E	P 1808						2007									0041	
	R:	AT,	BE,	BG,	CH,	CY,	CZ,	DE,	DK,	EE,	ES,	FI,	FR,	GB,	GR,	HU,	ΙE,
		IS,	IT,	LI,	LU,		NL,							TR			
	S 2007						2007									0060	526
	S 2007															0070	
	S 2008				A1		2008	0110		US 2						0070	
PRIORI	TY APE	PLN.	INFO	.:											A 2	0031	128
										GB 2					A 2	0040	407
										GB 2						0040	
																0041	
										WO 2						0041	
										US 2	006-	5805	52		A3 2	0060	526
OTHER GI	SOURCE	E(S):			MARI	PAT	143:	69829	9								

AB An organic semiconducting layer formulation (I), which comprises: an organic binder which has a permittivity, ϵ , at 1,000 Hz of 3.3 or less; and a polyacene compound of Formula: A: wherein: each of R1, R2, R3,

Ι

R4, R5, R6, R7, R8, R9, R10, R11 and R12, which may be the same or different, independently represents hydrogen; an optionally substituted C1-C40 carbyl or hydrocarbyl group; an optionally substituted C1-C40 alkoxy group; an optionally substituted C6-C40 aryloxy group; an optionally substituted C7-C40 alkylaryloxy group; an optionally substituted C2-C40 alkoxycarbonyl group; an optionally substituted C7-C40 aryloxycarbonyl group; a cyano group (-CN); a carbamoyl group (-C(= O)NH2); a haloformyl group (-C(= O)-X, wherein X represents a halogen atom); a formyl group (-C(= O)-H); an isocyano group; an isocyanate group; a thiocyanate group or a thioisocyanate group; an optionally substituted amino group; a hydroxy group. A nitro group; a CF3 group; a halo group (CI, Br, F); or an optionally substituted silyl group; and wherein independently each pair of R2 and R3 and/or R8 and R9, may be cross-bridged to form a C4-C40 saturated or unsatd. ring, which saturated or unsatd. ring may be intervened by an oxygen atom, a sulfur atom or a group shown by formula -N(Ra)- (wherein Ra is a hydrogen atom or an optionally substituted hydrocarbon group), or may optionally be substituted; and wherein one or more of the carbon atoms of the polyacene skeleton may optionally be substituted by a heteroatom selected from N, P, As, O, S, Se and Te; and wherein independently any two or more of the substituents R1-R12 which are located on adjacent ring positions of the polyacene may, together, optionally constitute a further C4-C40 saturated or unsatd. ring optionally interrupted by O, S or -N(Ra) where Ra is as defined above or an aromatic ring system, fused to the polyacene; and wherein n is 0, 1, 2, 3 or 4, also claimed is an electronic device, particularly.

IT 6006-83-3, 5,14-Pentacenedione 317809-68-0

373596-08-8 373596-09-9 398128-81-9

775324-33-9 775324-34-0 854519-90-7

854519-91-8 854519-92-9 854519-95-2

854519-96-3 854520-00-6

RL: DEV (Device component use); USES (Uses)

(improvements in and relating to organic semiconducting layers for organic FETs)

RN 6006-83-3 CAPLUS

CN 5,14-Pentacenedione (CA INDEX NAME)

RN 317809-68-0 CAPLUS

CN Pentacene, 6,13-bis[2-(trimethylsilyl)ethynyl]- (CA INDEX NAME)

RN 373596-08-8 CAPLUS

CN Pentacene, 6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)

RN 373596-09-9 CAPLUS

CN Pentacene, 5,14-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)

RN 398128-81-9 CAPLUS

CN Pentacene, 6,13-bis[2-(triethylsilyl)ethynyl]- (CA INDEX NAME)

RN 775324-33-9 CAPLUS

CN Anthra[2,3-b:6,7-b']dithiophene, 5,11-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)

RN 775324-34-0 CAPLUS

CN Silane, (anthra[2,3-b:7,6-b']dithiophene-5,11-diyldi-2,1-ethynediyl)bis[tris(1-methylethyl)- (9CI) (CA INDEX NAME)

RN 854519-90-7 CAPLUS

CN Pentacene, 2,3,9,10-tetramethyl-6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)

RN 854519-91-8 CAPLUS

CN Pentacene, 6,13-bis[2-(4-pentylphenyl)ethynyl]- (CA INDEX NAME)

RN 854519-92-9 CAPLUS

CN Dibenzo[1,pqr]benz[a]anthracene, 7,12-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)

854519-95-2 CAPLUS RN

Pentacene, 1,8-difluoro-6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl]-CN (CA INDEX NAME)

RN854519-96-3 CAPLUS

CN Pentacene, 1,11-difluoro-6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl]-(CA INDEX NAME)

RN 854520-00-6 CAPLUS

Pentacene, 2,3,9,10-tetrafluoro-6,13-bis[2-[tris(1-CN methylethyl)silyl]ethynyl]- (CA INDEX NAME)

L5 ANSWER 9 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER:

2004:965525 CAPLUS

DOCUMENT NUMBER:

141:419284

TITLE:

Valve acting metal sintered body, production method

therefor, and solid electrolytic capacitor

INVENTOR(S):

Omori, Kazuhiro; Shibuya, Yoshinori

PATENT ASSIGNEE(S):

Showa Denko K.K., Japan

SOURCE:

PCT Int. Appl., 112 pp.

CODEN: PIXXD2

DOCUMENT TYPE:

Patent

LANGUAGE:

English

FAMILY ACC. NUM. COUNT:

PA	PATENT NO. KIND DATE					APPLICATION NO.						DATE 						
WC	2004	0978	70		A1	_	2004	1111	1						2	0040	427	
	W:	AE,	AG,	AL,	AM,	AT,	ΑU,	ΑZ,	BA,	BB,	BG,	BR,	BW,	BY,	BZ,	CA,	CH,	
		CN,	CO,	CR,	CU,	CZ,	DE,	DK,	DM,	DZ,	EC,	EE,	EG,	ES,	FI,	GB,	GD,	
		GE,	GH,	GM,	HR,	HU,	ID,	IL,	IN,	IS,	KE,	KG,	ΚP,	KR,	ΚZ,	LC,	LK,	
		LR,	LS,	LT,	LU,	LV,	MA,	MD,	MG,	MK,	MN,	MW,	MX,	MZ,	NA,	NI,	NO,	
		NZ,	OM,	PG,	PH,	PL,	PT,	RO,	RU,	SC,	SD,	SE,	SG,	SK,	SL,	SY,	ТJ,	
		TM,	TN,	TR,	TT,	TZ,	UA,	UG,	US,	UZ,	VC,	VN,	YU,	ZA,	ZM,	ZW		
	RW:	BW,	GH,	GM,	KE,	LS,	MW,	ΜZ,	NA,	SD,	SL,	SZ,	ΤZ,	UG,	ZM,	ZW,	AM,	
		AZ,	BY,	KG,	ΚZ,	MD,	RU,	ТJ,	TM,	AT,	ΒE,	BG,	CH,	CY,	CZ,	DE,	DK,	
		EE,	ES,	FI,	FR,	GB,	GR,	HU,	ΙE,	IT,	LU,	MC,	NL,	PL,	PT,	RO,	SE,	
		SI,	SK,	TR,	BF,	ВJ,	CF,	CG,	CI,	CM,	GΑ,	GN,	GQ,	GW,	ML,	MR,	ΝE,	
		SN,	TD,	TG														
JP	2004	3496	83	•	Α		2004	1209		JP 2	004-	9622	3		2	0040	329	
EP	1618															0040		
	R:	AT,																
		ΙE,	SI,	LT,	LV,	FI,	RO,	MK,										HR
	1813							0802				8001						
US	2006	0279	908		A1		2006	1214										
PRIORIT	Y APP	LN.	INFO	.:								1232						
												4671						
							_					JP61						

The invention provides a valve-acting metal sintered body for anode of a AB solid electrolytic capacitor, having a high capacitance, well impregnated with cathode material, and exhibiting excellent properties particularly when having a large volume The provided capacitor has a low ESR, an excellent tan δ value, and good long-term reliability such as moisture resistance and heat resistance with the sintered body. The production method for the capacitor comprises the following steps: coating/printing/shaping a granulated product of a mixed dispersion containing a pore-forming agent, an organic binder, and a primary powder or secondary aggregated powder of 1 member selected from valve-acting metal, a valve-acting metal compound, and a valve-acting metal alloy or a granulated powder thereof and a solvent; or compressing and shaping the granulated product of a mixture obtained by removing the solvent from the dispersion; sintering the shaped article containing a pore-forming agent; and removing the pore-forming agent from the sintered body.

IT 193-44-2, Tetrathiotetracene

RL: DEV (Device component use); USES (Uses)

(organic semiconductor; valve acting metal sintered body, production method therefor, and solid electrolytic capacitor)

RN 193-44-2 CAPLUS

CN Naphthaceno[5,6-cd:11,12-c'd']bis[1,2]dithiole (CA INDEX NAME)

REFERENCE COUNT:

THERE ARE 38 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L5 ANSWER 10 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER:

2004:533195 CAPLUS

DOCUMENT NUMBER:

141:79294

TITLE:

Semiconductor compositions and

electrophotographic apparatus parts using them with

excellent heat, moisture, and voltage resistance

INVENTOR(S): Yoshikawa, Hitoshi; Iinuma, Sumio PATENT ASSIGNEE(S): Tokai Rubber Industries, Ltd., Japan

SOURCE: Jpn. Kokai Tokkyo Koho, 35 pp.

CODEN: JKXXAF

DOCUMENT TYPE: Patent LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 2004184513	Α	20040702	JP 2002-348351	20021129
JP 3960215	B2	20070815		
RIORITY APPLN. INFO.:			JP 2002-348351	20021129

OTHER SOURCE(S): MARPAT 141:79294

AB The compns., development rolls for electrophotog., contain elec. conductive polymers (A) having surfactant structures (sulfonic acid group-containing naphthalene or anthracene structures, preferably) and showing solubility to PhMe or Me Et ketone ≥20% and solubility to water <3% and binder polymers (B), thus improving compatibility of them.

IT 22582-76-9DP, 9-Anthracenesulfonic acid, polymers with aniline RL: DEV (Device component use); IMF (Industrial manufacture); POF (Polymer in formulation); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses)

(conductive polymer; semiconductor compns. containing conductive surfactant polymers with good heat, moisture, and voltage resistance for electrophotog. apparatus)

RN 22582-76-9 CAPLUS

CN 9-Anthracenesulfonic acid (CA INDEX NAME)

L5 ANSWER 11 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER: 2004:142824 CAPLUS

DOCUMENT NUMBER: 140:208704

TITLE: Crosslinkable fill compositions for uniformly

protecting via and contact holes

INVENTOR(S): Lamb, James E.; Shao, Xie

PATENT ASSIGNEE(S): USA

SOURCE: U.S. Pat. Appl. Publ., 22 pp., Cont.-in-part of U.S.

Ser. No. 196,603.

CODEN: USXXCO

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 2

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
US 20040034134	A1	20040219	US 2003-643398	20030819
US 20010056144	A1	20011227	US 2001-918110	20010730
US 20020041953	A1	20020411	US 2001-931264	20010816
US 20020016057	A1	20020207	US 2001-966208	20010927
US 20020183426	A 1	20021205	US 2002-196603	20020715
US 20030148601	A1	20030807	US 2003-366963	20030214

US 20040147108 US 7026237	A1 B2	20040729 20060411	US 2004-759447	20040116
US 20050159520	A1	20050721	US 2004-964288	20041013
PRIORITY APPLN. INFO.:			US 1999-383785	B1 19990826
			US 2000-632823	B1 20000807
			US 2001-918110	A1 20010730
			US 2002-196603	A2 20020715
			US 1999-440399	B1 19991115
			US 1999-460162	A1 19991213
			US 2001-966208	B1 20010927
			US 2003-366963	A1 20030214
			US 2003-643398	B1 20030819

AB The present invention is broadly concerned with fill compns. and methods useful for protecting the surfaces forming the contact and via holes during dual damascene processes for the production of integrated circuits. More particularly, the compns. of the invention comprise a quantity of solid crosslinkable components including a polymer binder, and a solvent system for the solid components. A via and contact hole fill composition and method for using the composition in the dual damascene production of

circuits is provided. Broadly, the fill compns. include a quantity of solid components including a polymer binder and a solvent system for the solid components. The b.p. of the solvent system is less than the crosslinking temperature of the composition Preferred solvents for use in the solvent system include those selected from the group consisting of alcs., ethers, glycol ethers, amides, ketones, and mixts. thereof. Preferred polymer binders are those having an aliphatic backbone and a mol. weight of .ltorsim.80,000, with polyesters being particularly preferred. In use, the fill composition is applied to the substrate surfaces forming the contact or via holes as well as to the substrate surfaces surrounding the holes, followed by heating to the composition reflow temperature so as to cause the composition

to uniformly flow into and cover the hole-forming surfaces and substrate surfaces. The composition is then cured, and the remainder of the dual damascene process is carried out.

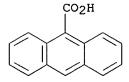
IT 723-62-6, 9-Anthracenecarboxylic acid

RL: NUU (Other use, unclassified); PEP (Physical, engineering or chemical process); PYP (Physical process); PROC (Process); USES (Uses)

(in preparation of polymeric fill material for protecting via and contact hole surfaces during dual damascene processes for integrated-circuit fabrication)

RN 723-62-6 CAPLUS

CN 9-Anthracenecarboxylic acid (CA INDEX NAME)



L5 ANSWER 12 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER:

2004:78554 CAPLUS

DOCUMENT NUMBER:

140:154111

TITLE:

Electroluminescent device and methods for its

production and use

INVENTOR(S):

Kinlen, Patrick J.

PATENT ASSIGNEE(S):

Crosslink Polymer Research, USA

SOURCE:

U.S. Pat. Appl. Publ., 22 pp., Cont.-in-part of U.S.

Ser. No. 207,576. CODEN: USXXCO

DOCUMENT TYPE:

Patent English

LANGUAGE: FAMILY ACC. NUM. COUNT:

. 2

PATENT INFORMATION:

	PAT	TENT I	NO.			KINI	D	DATE				ICAT		NO.		D	ATE	
		2004						2004		1				76		2	0030	128
		7361				B2		2008						. .				
		2004		379				2004			US 2	002-	2075	76		2	0020	129
		7029				В2		2006										
	CA	2493	153			A1		2004	0205	•	CA 2	003-	2493	153		2	0030.	718
	WO	2004	0112	50		A1		2004	0205	1	WO 2	003-	US22	473	20030718			
		W:	ΑE,	AG,	AL,	AM,	ΑT,	ΑU,	ΑZ,	BA,	BB,	BG,	BR,	BY,	BZ,	CA,	CH,	CN,
								DK,										
								IN,										
								MD,										
								RU,										
								US,		-						,	,	,
		₽W•	•	•	•	•	•	MZ,	•	•	-	•	•	•		ΔM	Δ7.	RV
		KW.		-				TM,	•	•	•	•	•	•	•	•	•	•
											•	•	•			•	•	•
								IE,		-						-	-	-
		0000	•	-	•	•		CM,		•			•	•	•			
		2003																
	EΡ	1542																
		R:	-	•			•	ES,	•		•	•	•			•		PT,
	•		•		•	•	•	RO,	-	•			•	•	•			
	JP	2005	5350	77		T		2005	1117		JP 2	004-	5246	40		20	0030,	718
PRIO	RITY	APP:	LN.	INFO	. :					1	US 2	002-	2075	76	1	A2 2	0020	729
•										1	US 2	003-	3524	76	7	A 20	0030	128
										1	WO 2	003-	US22	473	Ţ	v 2	0030	718
7 D	70 7					_ : _	-1		1									1

AB A luminescent device is described comprises an electroluminescent phosphor in operative contact with a light-emitting material wherein excitation of the electroluminescent phosphor by an a.c. elec. field causes the emission of light by the light-emitting material, and wherein the electrodes may comprise an intrinsically conductive polymer. Methods of fabricating the device and using it in an electroluminescent display are also described.

IT 92-24-0, Tetracene 120-12-7, Anthracene, uses

62555-84-4 474975-19-4 474975-22-9

RL: DEV (Device component use); USES (Uses)

(light-emitting material; a.c.-powered electroluminescent device and fabrication method)

RN 92-24-0 CAPLUS

CN Naphthacene (CA INDEX NAME)

RN 120-12-7 CAPLUS

CN Anthracene (CA INDEX NAME)

RN 62555-84-4 CAPLUS

CN 9H-Carbazole, 3,3'-(9,10-anthracenediyldi-2,1-ethenediyl)bis[9-ethyl- (CA INDEX NAME)

PAGE 2-A

RN 474975-19-4 CAPLUS

CN Poly[9,10-anthracenediyl-1,2-ethenediyl(9,9-dioctyl-9H-fluorene-2,7-diyl)-1,2-ethenediyl] (CA INDEX NAME)

RN 474975-22-9 CAPLUS

CN Poly[9,10-anthracenediyl(9,9-dihexyl-9H-fluorene-2,7-diyl)] (CA INDEX NAME)

REFERENCE COUNT:

94 THERE ARE 94 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L5 ANSWER 13 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER:

2004:78550 CAPLUS

DOCUMENT NUMBER:

140:154092

TITLE:

Light-emitting phosphor particles and

electroluminescent devices employing same

INVENTOR(S):

Kinlen, Patrick J.

PATENT ASSIGNEE(S):

USA

SOURCE:

U.S. Pat. Appl. Publ., 18 pp.

CODEN: USXXCO

DOCUMENT TYPE:

Patent

LANGUAGE:

English

FAMILY ACC. NUM. COUNT:

	ENT I				KIN	D	DATE				ICAT:					ATE	
US 20040018379								0129	1		002-				20020729		
US 7029763					В2		2006	0418									
US 20040018382					A1		2004	0129	1	US 2	003-	3524	76		20030128		
US 7361413				B2		2008	0422										
CA	2493	153			A 1		2004	0205		CA 2	003-	2493	153		2	0030	718
WO	2004	0112	50		A 1		2004	0205	1	WO 2	003-1	JS22	473		2	0030.	718
	W:	AE,	AG,	AL,	AM,	AT,	AU,	AZ,	BA,	BB,	BG,	BR,	BY,	BZ.	CA.	CH,	CN.
										-		-	-	-	-	GE,	•
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		•	•	•	-	•		-	•	•	•	•	•	•	•	NZ,	•
					-				•	•	•	•	•	•	•	TM,	•
			•		-			UZ,	•	•	•	•	•	•	10,	,	111,
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	2003																
EP	EP 1542867													20030718			
	R:															MC,	PT,
		ΙE,	SI,	LT,	LV,	FI,	RO,	MK,	CY,	AL,	TR,	BG,	CZ,	EE,	HU,	SK	

JP 2005535077	T	20051117	JP	2004-524640		20030718
US 20060127670	A1	20060615	US	2006-344934		20060201
us 7303827	B2	20071204				
PRIORITY APPLN. INFO.:			US	2002-207576	A2	20020729
			US	2003-352476	Α	20030128
			WO	2003-US22473	W	20030718

AB Phosphor particles are described which are coated with a light-emitting substance (e.g., a light-emitting polymer and/or a light-emitting small mol.). Methods of preparing the coated phosphors are described which entail coating phosphor particles with a light-emiting material. Electroluminescent displays employing the phosphors are also described. Methods for fabricating electroluminescent displays are described which entail formulating an ink by mixing phosphor particles with ≥1 binder polymer; depositing a conducting rear electrode onto a substrate in a pattern; depositing the ink onto the rear electrode to form a layer; optionally depositing a layer containing a light-emitting substance onto the layer; optionally depositing a transparent hole transporting electrode onto the layer; and depositing a front outlining electrode; and depositing connection leads to the rear electrode and the front outlining electrode.

IT 62555-84-4 474975-19-4 474975-22-9

RL: DEV (Device component use); USES (Uses)

(phosphor particles with light-emitting coatings and their preparation and electroluminescent displays employing them and their fabrication)

RN 62555-84-4 CAPLUS

CN 9H-Carbazole, 3,3'-(9,10-anthracenediyldi-2,1-ethenediyl)bis[9-ethyl- (CA INDEX NAME)

PAGE 1-A

RN 474975-19-4 CAPLUS

CN Poly[9,10-anthracenediyl-1,2-ethenediyl(9,9-dioctyl-9H-fluorene-2,7-diyl)-1,2-ethenediyl] (CA INDEX NAME)

RN 474975-22-9 CAPLUS

CN Poly[9,10-anthracenediyl(9,9-dihexyl-9H-fluorene-2,7-diyl)] (CA INDEX NAME)

REFERENCE COUNT:

91 THERE ARE 91 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L5 ANSWER 14 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER:

2002:849341 CAPLUS

DOCUMENT NUMBER:

137:377516

TITLE:

Electroluminescent devices fabricated with encapsulated light emitting polymer particles

INVENTOR(S):

Murasko, Matthew; Kinlen, Patrick J.; St. John, Brent

PATENT ASSIGNEE(S): SOURCE:

Lumimove, Inc., USA PCT Int. Appl., 21 pp.

CODEN: PIXXD2

DOCUMENT TYPE: LANGUAGE: Patent English

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

PA'	PATENT NO.					KIND DATE				APPLICATION NO.						DATE		
	WO 2002087308 WO 2002087308						WO 2002-US13547						20020430					
	W: RW:	CO, GM, LS, RO, VN, GH, KG,	CR, HR, LT, RU, YU, GM, KZ,	CU, HU, LU, SD, ZA, KE, MD,	CZ, ID, LV, SE, ZW LS, RU,	DE, IL, MA, SG, MW, TJ,	DK, IN, MD, SI, MZ, TM,	DM, IS, MG, SK, SD, AT,	DZ, JP, MK, SL, SL, BE,	EC, KE, MN, TJ, SZ, CH,	BG, EE, KG, MW, TM,	ES, KP, MX, TR, UG, DE,	FI, KR, MZ, TT, ZM, DK,	GB, KZ, NO, TZ, ZW, ES,	GD, LC, NZ, UA, AM, FI,	GE, LK, PL, UG, AZ, FR,	GH, LR, PT, UZ, BY, GB,	
								SN,			BF,	в,	CF,	CG,	CI,	CM,	GA,	
CA	2473	969			A1		2002	1107		CA 2	2002-:	2473	969		2	0020	430	
AU	2002	2590	77		A1		2002	1111		AU 2	2002-:	2590	77		2	0020	430	
US	2003	0032							1	US 2	2002-	1355	99		2	0020	430	
US	7001	639			B2		2006	0221										
US	2006	0251	798		A 1		2006	1109	1	US 2	2005-	2607	38		2	0051	027	
PRIORIT	Y APP	LN.	INFO	.:					7	US 2	2001-	2873	21P	1	P 2	0010	430	
											2001-			-	P 2	0010	430	
									1	US 2	2002-	1355	99	i	A3 2	0020	430	
									1	WO 2	2002-1	US13	547	I	W 2	0020	430 .	

AB Methods for fabricating electroluminescent display devices are described which entail encapsulating organic light-emitting material particles with a conductive polymer; formulating an ink by mixing the encapsulated particles with binder polymers; depositing a conducting rear electrode onto a substrate in a pattern; depositing the ink onto rear electrode patterns to form a light-emitting layer; depositing a transparent hole transporting electrode onto the light-emitting layer; depositing a front outlining electrode onto the hole transporting electrode; and depositing connection leads to the rear electrode and the front outlining electrode.

IT 62555-84-4 474975-19-4 474975-22-9

RL: DEV (Device component use); USES (Uses)

(electroluminescent display fabrication using polymer-encapsulated light-emitting particles)

RN 62555-84-4 CAPLUS

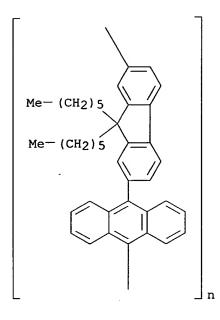
CN 9H-Carbazole, 3,3'-(9,10-anthracenediyldi-2,1-ethenediyl)bis[9-ethyl- (CA INDEX NAME)

RN 474975-19-4 CAPLUS

CN Poly[9,10-anthracenediyl-1,2-ethenediyl(9,9-dioctyl-9H-fluorene-2,7-diyl)-1,2-ethenediyl] (CA INDEX NAME)

RN 474975-22-9 CAPLUS

CN Poly[9,10-anthracenediyl(9,9-dihexyl-9H-fluorene-2,7-diyl)] (CA INDEX NAME)



ANSWER 15 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER:

2001:798567 CAPLUS

DOCUMENT NUMBER:

135:326222

TITLE:

Production method for Niobium sintered body and

capacitor

INVENTOR(S):

Naito, Kazumi; Kabe, Isao Showa Denko K.K., Japan

PATENT ASSIGNEE(S): SOURCE:

PCT Int. Appl., 27 pp. CODEN: PIXXD2

DOCUMENT TYPE:

Patent

LANGUAGE:

English

FAMILY ACC. NUM. COUNT:

PATENT NO.					KIN	D -	DATE	· 		APPLICATION NO.						DATE		
WO 2001082318 WO 2001082318										WO 2001-JP3389						20010420		
		AE, CO, HR, LV,	AG, CR, HU, MA, SG,	AL, CU, ID, MD,	AM, CZ, IL, MG,	AT, DE, IN, MK,	AU, DK, IS, MN,	AZ, DM, KE, MW,	DZ, KG, MX,	EE, KR, MZ,	BG, ES, KZ, NO, TZ,	FI, LC, NZ,	GB, LK, PL,	GD, LR, PT,	GE, LS, RO,	GH, LT, RU,	GM, LU, SD,	
	RW:	GH, DE,	GM, DK,	ES,	FI,	FR,	GB,	GR,	IE,	IT,	TZ, LU, MR,	MC,	NL,	PT,	SE,			
JP EP	2002	0488 0089 125	05 52		A A A2		2001 2002 2003	1107 0111 0115		AU 2 JP 2	001- 001- 001-	4880 1221	5 54	·	2	0010	420	
BR CN AT KR US	R: 2001	AT, IE, 0101 643 59 67 0172	BE, SI, 73	CH, LT,	DE, LV, A A T B1	DK, FI,	ES, RO, 2003 2004 2007	FR, MK, 0305 0623 0315 0823 0918	GB, CY,	AL, BR 2 CN 2 AT 2 KR 2	IT, TR 001- 001- 001- 002- 003-	1017 8082 9219 7140	3 96 42 39		2 2 2	0010 0010 0010	420 420 420 018	

JP 2000-121244 A 20000421 Р US 2000-233438P 20000918 W WO 2001-JP3389

A Nb sintered body which is prepared in such a manner that a Nb powder is AB sintered at a temperature of 500° to 2000° and allowed to stand at a maximum sintering temperature for 60 min to 150 min in sintering. The Nb sintered body of the present invention is characterized in that (CV) of a capacitance (C) per unit mass and a forming voltage (V) is 90,000 $\mu F.V/g$ or more, and a value obtained by dividing a product of a mean particle diameter (D50) of a primary particle of the Nb powder and a leakage current (LC) by the CV is 5 x $10-4~\mu m.\mu A$ ($\mu F.V$) or less. And there can be provided a well-balanced capacitor with respect to a preferably low leakage current value regardless of the large capacitance, i.e., a highly reliable capacitance.

193-44-2, Tetrathiotetracene IT

RL: DEV (Device component use); USES (Uses)

(organic semiconductor; production method for niobium sintered body and capacitor)

RN 193-44-2 CAPLUS

Naphthaceno[5,6-cd:11,12-c'd']bis[1,2]dithiole (CA INDEX NAME) CN

ANSWER 16 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER:

2001:152968 CAPLUS

DOCUMENT NUMBER:

134:187113

TITLE:

Improved polymeric fill material for protecting via

and contact hole surfaces during dual damascene processes for integrated-circuit fabrication

INVENTOR(S):

Lamb, James E., III; Shao, Xie

PATENT ASSIGNEE(S):

Brewer Science, USA

SOURCE:

PCT Int. Appl., 45 pp. CODEN: PIXXD2

DOCUMENT TYPE:

Patent

LANGUAGE:

English

FAMILY ACC. NUM. COUNT:

PA!	CENT :	NO.			KIN	KIND DATE			APPLICATION NO.						DATE			
						-												
WO	WO 2001015211				A1		2001	0301	,	WO 2000-US22839						20000817		
	W:	ΑE,	AG,	AL,	AM,	ΑT,	AU,	ΑZ,	BA,	BB,	BG,	BR,	BY,	BZ,	CA,	CH,	CN,	
		CR,	CU,	CZ,	DE,	DK,	DM,	DZ,	EE,	ES,	FI,	GB,	GD,	GE,	GH,	GM,	HR,	
		HU,	ID,	IL,	IN,	.IS,	JP,	ΚE,	KG,	KP,	KR,	ΚZ,	LC,	LK,	LR,	LS,	LT,	
		LU,	LV,	MA,	MD,	MG,	MK,	MN,	MW,	MX,	MZ,	NO,	NZ,	PL,	PT,	RO,	RU,	
		SD,	SE,	SG,	SI,	SK,	SL,	ТJ,	TM,	TR,	TT,	TZ,	UA,	ŬĠ,	UZ,	VN,	YU,	
		ZA,	zw															
	RW:	GH,	GM,	KE,	LS,	MW,	MZ,	SD,	SL,	SZ,	TZ,	UG,	ZW,	AT,	BE,	CH,	CY,	
		DE,	DK,	ES,	FI,	FR,	GB,	GR,	IE,	IT,	LU,	MC,	NL,	PT,	SE,	BF,	ВJ,	
		CF,	CG,	CI,	CM,	GΑ,	GN,	GW,	ML,	MR,	NE,	SN,	TD,	TG				
EP	P 1212788				A1		2002	0612	EP 2000-955751						20000817			
	R:	AT,	BE,	CH,	DE,	DK,	ES,	FR,	GB,	GR,	IT,	LI,	LU,	NL,	SE,	MC,	PT,	
		ΙE,	SI,	LT,	LV,	FI,	RO,	MK,	CY,	AL		•						
JP	2003	5088	94		${f T}$		2003	0304		JP 2	001-	5194	78		2	0000	817	

CN 1/50275		20050024	~ 17	2005-10009197		20000817
CN 1658375	Α	20050824	CN	2005-10009197		20000817
TW 290343	В	20071121	TW	2000-89117234		20000825
US 20020041953	A1	20020411	US	2001-931264		20010816
US 20020016057	A1	20020207	US	2001-966208		20010927
US 20030148601	A1	20030807	US	2003-366963		20030214
US 20040147108	A1	20040729	US	2004-759447		20040116
US 7026237	B2	20060411				
PRIORITY APPLN. INFO.:			US	1999-383785	Α	19990826
			US	1999-440399	В1	19991115
			US	1999-460162	A1	19991213
			WO	2000-US22839	W	20000817
			US	2001-966208	В1	20010927
			US	2003-366963	A1	20030214

An improved via and contact hole fill composition and method for using the composition in the dual damascene production of circuits is provided. Broadly, the

fill compns. include a quantity of solid components including a polymer binder and a solvent system for the solid components. The b.p. of the solvent system is less than the crosslinking temperature of the composition Preferred solvents for use in the solvent system include those selected from the group consisting of alcs., ethers, glycol ethers, amides, ketones, and mixts. thereof. Preferred polymer binders are those having an aliphatic backbone and a mol. weight of .ltorsim.80,000, with polyesters being particularly preferred. In use, the fill composition is applied to the substrate surfaces forming the contact or via holes as well as to the substrate surfaces surrounding the holes, followed by heating to the composition reflow temperature so as to cause the composition to uniformly flow into and

cover the hole-forming surfaces and substrate surfaces. The composition is then cured, and the remainder of the dual damascene process is carried

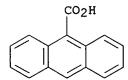
723-62-6, 9-Anthracenecarboxylic acid IT

> RL: NUU (Other use, unclassified); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)

(in preparation of polymeric fill material for protecting via and contact hole surfaces during dual damascene processes for integrated-circuit fabrication)

723-62-6 CAPLUS RN

9-Anthracenecarboxylic acid (CA INDEX NAME) CN



7 THERE ARE 7 CITED REFERENCES AVAILABLE FOR THIS REFERENCE COUNT: RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

ANSWER 17 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER: 2000:665563 CAPLUS

133:253993 DOCUMENT NUMBER:

TITLE: Acrylic antireflective coatings and their manufacture

for use in microlithography in fabrication of

semiconductor devices

Jung, Min-ho; Hong, Sung-eun; Baik, Ki-ho INVENTOR(S):

Hyundai Electronics Industries Co., ltd., S. Korea PATENT ASSIGNEE(S):

SOURCE: Ger. Offen., 18 pp.

CODEN: GWXXBX

DOCUMENT TYPE: Patent LANGUAGE: German

PATENT NO.	KIND	DATE	APPLICATION NO.		DATE
DE 19962663	A1	20000921	DE 1999-19962663		19991223
KR 2000060410	A	20001016	KR 1999-8668		19990315
TW 234689	В	20050621	TW 1999-88120016		19991117
GB 2347927	Α	20000920	GB 1999-27834		19991126
GB 2347927	В	20040324			
FR 2791056	A1	20000922	FR 1999-15748		19991214
FR 2791056	B1	20040102			
JP 2000264921	Α	20000926	JP 1999-354492		19991214
IT 99TO1092	A1	20010614	IT 1999-TO1092		19991214
IT 1308671	B1	20020109			
CN 1266843	Α	20000920	CN 1999-126380		19991215
us 6309790	B1	20011030	US 2000-499873		20000207
NL 1014639	A1	20000918	NL 2000-1014639		20000314
NL 1014639	C2	20011228			
ORTTY APPIN THEO .			KR 1999-8668	Δ	19990315

PRIORITY APPLN. INFO.: KR 1999-8668

Acrylic antireflective coatings with higher etching speed in microlithog. using 248 Nm KrF-, 193 Nm ArF- and 157 Nm F2-Lasers are based on polymers having anthracene (derivative), hydroxyalkyl, oxiranylalkyl, and, optionally, Me side chains and optionally contain suitable anthracene (derivative) chromophores. A typical polymer was manufactured by radical polymerization of 9-anthrylmethyl acrylate 0.5, 2-hydroxyethyl acrylate 0.3, and glycidyl methacrylate 0.2 mol.

294673-25-9P 294673-27-1P 294673-28-2P IT

294673-29-3P 294673-30-6P 294673-31-7P

294673-32-8P 294673-33-9P 294673-34-0P

294673-35-1P 294673-36-2P 294673-37-3P

294673-38-4P 294673-39-5P 294673-41-9P

294673-42-0P 294673-43-1P 294673-44-2P

294673-45-3P 294673-46-4P

RL: IMF (Industrial manufacture); POF (Polymer in formulation); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses) (acrylic antireflective coatings for use in microlithog. in fabrication of semiconductor devices)

294673-25-9 CAPLUS RN

2-Propenoic acid, 2-methyl-, oxiranylmethyl ester, polymer with CN 9-anthracenylmethyl 2-propenoate and 2-hydroxyethyl 2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-34-8 CMF C18 H14 O2

CM

CRN 818-61-1 CMF C5 H8 O3

$$\begin{array}{c} {\rm o} \\ || \\ {\rm ho-ch_2-ch_2-o-c-ch} \end{array}$$

CM 3

CRN 106-91-2 CMF C7 H10 O3

$$\overset{\text{O}}{\longleftarrow} \overset{\text{O}}{\underset{\text{CH}_2-\text{O}-\text{C}-\text{C}-\text{Me}}{\text{Me}}}$$

RN 294673-27-1 CAPLUS

CN 2-Propenoic acid, 2-methyl-, oxiranylmethyl ester, polymer with 9-anthracenylmethyl 2-propenoate and 3-hydroxypropyl 2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-34-8 CMF C18 H14 O2

CM 2

CRN 2761-08-2 CMF C6 H10 O3

CM 3

CRN 106-91-2 CMF C7 H10 O3

RN 294673-28-2 CAPLUS

CN 2-Propenoic acid, 9-anthracenylmethyl ester, polymer with 2-hydroxyethyl 2-propenoate and oxiranylmethyl 2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-34-8 CMF C18 H14 O2

CM 2

CRN 818-61-1 CMF C5 H8 O3

$$\begin{array}{c} \text{O} \\ || \\ \text{HO-CH}_2\text{-CH}_2\text{-O-C-CH-----} \text{CH}_2 \end{array}$$

CM 3

CRN 106-90-1 CMF C6 H8 O3

RN 294673-29-3 CAPLUS

CN 2-Propenoic acid, 9-anthracenylmethyl ester, polymer with 3-hydroxypropyl 2-propenoate and oxiranylmethyl 2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-34-8 CMF C18 H14 O2

CM 2

CRN 2761-08-2 CMF C6 H10 O3

CM 3

CRN 106-90-1 CMF C6 H8 O3

RN 294673-30-6 CAPLUS

CN 2-Propenoic acid, 9-anthracenylmethyl ester, polymer with 4-hydroxybutyl 2-propenoate and oxiranylmethyl 2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-34-8 CMF C18 H14 O2

CM 2

CRN 2478-10-6 CMF C7 H12 O3

$$\begin{array}{c} \text{O} \\ || \\ \text{HO- (CH}_2)_4 - \text{O-C-CH} \end{array} \text{CH}_2$$

CM 3

CRN 106-90-1 CMF C6 H8 O3

RN 294673-31-7 CAPLUS

CN 2-Propenoic acid, 2-methyl-, 9-anthracenylmethyl ester, polymer with 2-hydroxyethyl 2-propenoate and oxiranylmethyl 2-methyl-2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-35-9 CMF C19 H16 O2

CM 2

CRN 818-61-1 CMF C5 H8 O3

$$\begin{array}{c} \text{O} \\ || \\ \text{HO-CH}_2\text{--CH}_2\text{--O-C-CH} \end{array} \text{CH}_2$$

CM 3

CRN 106-91-2 CMF C7 H10 O3

$$\overset{\text{O}}{\longleftarrow} \overset{\text{O}}{\underset{\text{CH}_2-\text{O}-\text{C}-\text{C}-\text{Me}}{\text{M}}}$$

RN 294673-32-8 CAPLUS

CN 2-Propenoic acid, 2-methyl-, 9-anthracenylmethyl ester, polymer with 3-hydroxypropyl 2-propenoate and oxiranylmethyl 2-methyl-2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-35-9 CMF C19 H16 O2

CRN 2761-08-2 CMF C6 H10 O3

CM 3

CRN 106-91-2 CMF C7 H10 O3

$$\begin{tabular}{c|c} O & O & CH_2 \\ \hline & & \parallel & \parallel \\ CH_2-O-C-C-Me \\ \hline \end{tabular}$$

RN 294673-33-9 CAPLUS

CN 2-Propenoic acid, 2-methyl-, 9-anthracenylmethyl ester, polymer with 4-hydroxybutyl 2-propenoate and oxiranylmethyl 2-methyl-2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-35-9 CMF C19 H16 O2

CM 2

CRN 2478-10-6 CMF C7 H12 O3

CRN 106-91-2 CMF C7 H10 O3

RN 294673-34-0 CAPLUS

CN 2-Propenoic acid, 2-methyl-, 9-anthracenylmethyl ester, polymer with 2-hydroxyethyl 2-propenoate and oxiranylmethyl 2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-35-9 CMF C19 H16 O2

CM 2

CRN 818-61-1 CMF C5 H8 O3

$$0 \\ || \\ HO-CH_2-CH_2-O-C-CH == CH_2$$

CM 3

CRN 106-90-1 CMF C6 H8 O3

$$\begin{array}{c|c}
\circ & \circ \\
 & \parallel \\
 & \text{CH}_2 - \circ - \circ - \circ + = \circ \\
\end{array}$$

RN 294673-35-1 CAPLUS

CN 2-Propenoic acid, 2-methyl-, 9-anthracenylmethyl ester, polymer with 3-hydroxypropyl 2-propenoate and oxiranylmethyl 2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-35-9 CMF C19 H16 O2

CM 2

CRN 2761-08-2 CMF C6 H10 O3

$$0 \\ || \\ HO- (CH2)3-O-C-CH = CH2$$

CM 3

CRN 106-90-1 CMF C6 H8 O3

RN 294673-36-2 CAPLUS

CN 2-Propenoic acid, 2-methyl-, 9-anthracenylmethyl ester, polymer with 4-hydroxybutyl 2-propenoate and oxiranylmethyl 2-propenoate (9CI) (CA INDEX NAME)

CM · 1

CRN 2478-10-6 CMF C7 H12 O3

$$^{\circ}_{\parallel}$$
 $^{\circ}_{HO- (CH_2)_4-O-C-CH} = CH_2$

CM 3

CRN 106-90-1 CMF C6 H8 O3

RN 294673-37-3 CAPLUS

CN 2-Propenoic acid, 2-methyl-, methyl ester, polymer with 9-anthracenylmethyl 2-propenoate, 2-hydroxyethyl 2-propenoate and oxiranylmethyl 2-methyl-2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-34-8 CMF C18 H14 O2

CM 2

CRN 818-61-1 CMF C5 H8 O3

$$\begin{array}{c|c} & \circ \\ || \\ \text{HO-CH}_2\text{--CH}_2\text{--O-C-CH} \end{array} \text{CH}_2$$

CM 3

CRN 106-91-2 CMF C7 H10 O3

$$\overset{\text{O}}{\stackrel{\text{CH}_2}{\longrightarrow}} \overset{\text{O}}{\underset{\text{CH}_2-\text{O}-\text{C}-\text{C}-\text{Me}}{\text{Me}}}$$

CRN 80-62-6 CMF C5 H8 O2

$$^{\text{H}_2\text{C}}_{\parallel}$$
 $^{\text{O}}_{\parallel}$ $^{\text{Me}-\text{C}-\text{C}-\text{OMe}}$

RN 294673-38-4 CAPLUS

CN 2-Propenoic acid, 2-methyl-, methyl ester, polymer with 9-anthracenylmethyl 2-propenoate, 3-hydroxypropyl 2-propenoate and oxiranylmethyl 2-methyl-2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-34-8 CMF C18 H14 O2

CM 2

CRN 2761-08-2 CMF C6 H10 O3

CM 3

CRN 106-91-2 CMF C7 H10 O3

CRN 80-62-6 CMF C5 H8 O2

RN 294673-39-5 CAPLUS

CN 2-Propenoic acid, 2-methyl-, methyl ester, polymer with 9-anthracenylmethyl 2-propenoate, 2-hydroxyethyl 2-propenoate and oxiranylmethyl 2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-34-8 CMF C18 H14 O2

CM 2

CRN 818-61-1 CMF C5 H8 O3

$$0 \\ | \\ | \\ HO-CH_2-CH_2-O-C-CH = CH_2$$

CM 3

CRN 106-90-1 CMF C6 H8 O3

CM 4

CRN 80-62-6 CMF C5 H8 O2

RN 294673-41-9 CAPLUS

CN 2-Propenoic acid, 2-methyl-, methyl ester, polymer with 9-anthracenylmethyl 2-propenoate, 4-hydroxybutyl 2-propenoate and oxiranylmethyl 2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-34-8 CMF C18 H14 O2

CM 2

CRN 2478-10-6 CMF C7 H12 O3

$$0 \\ || \\ HO- (CH2)4-O-C-CH = CH2$$

CM 3

CRN 106-90-1 CMF C6 H8 O3

CM 4

CRN 80-62-6 CMF C5 H8 O2

$$\begin{array}{c|c} ^{H_2C} & \text{O} \\ \parallel & \parallel \\ \text{Me-} & \text{C-} & \text{C-} & \text{OMe} \end{array}$$

RN 294673-42-0 CAPLUS

CN 2-Propenoic acid, 2-methyl-, 9-anthracenylmethyl ester, polymer with 2-hydroxyethyl 2-propenoate, methyl 2-methyl-2-propenoate and oxiranylmethyl 2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-35-9 CMF C19 H16 O2

CM 2

CRN 818-61-1 CMF C5 H8 O3

CM 3

CRN 106-90-1 CMF C6 H8 O3

CM 4

CRN 80-62-6 CMF C5 H8 O2

RN 294673-43-1 CAPLUS

CN 2-Propenoic acid, 2-methyl-, 9-anthracenylmethyl ester, polymer with 3-hydroxypropyl 2-propenoate, methyl 2-methyl-2-propenoate and oxiranylmethyl 2-methyl-2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-35-9

CRN 2761-08-2 CMF C6 H10 O3

CM 3

CRN 106-91-2 CMF C7 H10 O3

$$\overset{\text{O}}{\longleftarrow} \overset{\text{O}}{\underset{\text{CH}_2-\text{O}-\text{C}-\text{C}-\text{Me}}{\text{Me}}} \overset{\text{CH}_2}{\underset{\text{CH}_2-\text{O}-\text{C}-\text{C}-\text{Me}}{\text{Me}}}$$

CM 4

CRN 80-62-6 CMF C5 H8 O2

RN 294673-44-2 CAPLUS

CN 2-Propenoic acid, 2-methyl-, 9-anthracenylmethyl ester, polymer with 4-hydroxybutyl 2-propenoate, methyl 2-methyl-2-propenoate and oxiranylmethyl 2-methyl-2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 2478-10-6 CMF C7 H12 O3

$$^{\circ}_{\parallel}$$
 $^{\circ}_{HO^{-}(CH_{2})_{4}-O^{-}C^{-}CH}$
 $^{\circ}_{CH_{2}}CH_{2}$

CM 3

CRN 106-91-2 CMF C7 H10 O3

CM 4

CRN 80-62-6 CMF C5 H8 O2

$$\begin{array}{c|c} ^{H_2C} & \text{O} \\ \parallel & \parallel \\ \text{Me-} & \text{C-} & \text{C-} & \text{OMe} \end{array}$$

RN 294673-45-3 CAPLUS

CN 2-Propenoic acid, 2-methyl-, 9-anthracenylmethyl ester, polymer with 3-hydroxypropyl 2-propenoate, methyl 2-methyl-2-propenoate and oxiranylmethyl 2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 2761-08-2 CMF C6 H10 O3

CM 3

CRN 106-90-1 CMF C6 H8 O3

CM 4

CRN 80-62-6 CMF C5 H8 O2

RN 294673-46-4 CAPLUS

CN 2-Propenoic acid, 2-methyl-, 9-anthracenylmethyl ester, polymer with 4-hydroxybutyl 2-propenoate, methyl 2-methyl-2-propenoate and oxiranylmethyl 2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 2478-10-6 CMF C7 H12 O3

CM 3

CRN 106-90-1 CMF C6 H8 O3

CM 4

CRN 80-62-6 CMF C5 H8 O2

IT 31645-35-9P, 9-Anthrylmethyl methacrylate

RL: IMF (Industrial manufacture); RCT (Reactant); PREP (Preparation); RACT (Reactant or reagent)

(acrylic antireflective coatings for use in microlithog. in fabrication of semiconductor devices)

RN 31645-35-9 CAPLUS

CN 2-Propenoic acid, 2-methyl-, 9-anthracenylmethyl ester (CA INDEX NAME)

IT 294673-40-8P

RL: IMF (Industrial manufacture); POF (Polymer in formulation); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses) (binder; acrylic antireflective coatings for use in microlithog. in fabrication of semiconductor devices)

RN 294673-40-8 CAPLUS

CN 2-Propenoic acid, 2-methyl-, methyl ester, polymer with 9-anthracenylmethyl 2-propenoate, 3-hydroxypropyl 2-propenoate and oxiranylmethyl 2-propenoate (9CI) (CA INDEX NAME)

CM 1

CRN 31645-34-8 CMF C18 H14 O2

CM 2

CRN 2761-08-2 CMF C6 H10 O3

$$0$$
 \parallel
 $HO-(CH2)3-O-C-CH=CH2$

CM 3

CRN 106-90-1 CMF C6 H8 O3

CM 4

CRN 80-62-6 CMF C5 H8 O2

IT 120-12-7, Anthracene, uses 577-33-3,

1,2,10-Anthracenetriol 642-31-9, 9-Anthraldehyde 723-62-6, 9-Anthracenecarboxylic acid 1143-38-0, Dithranol 1210-12-4, 9-Anthracenecarbonitrile 18004-57-4, 9-Anthraldehyde oxime 53531-31-0, 9-Anthryl trifluoromethyl ketone

RL: MOA (Modifier or additive use); TEM (Technical or engineered material use); USES (Uses)

(chromophore additive; acrylic antireflective coatings for use in microlithog. in fabrication of semiconductor devices)

RN 120-12-7 CAPLUS

CN Anthracene (CA INDEX NAME)

RN 577-33-3 CAPLUS

CN 1,2,10-Anthracenetriol (CA INDEX NAME)

RN 642-31-9 CAPLUS

CN 9-Anthracenecarboxaldehyde (CA INDEX NAME)

RN 723-62-6 CAPLUS

CN 9-Anthracenecarboxylic acid (CA INDEX NAME)

RN 1143-38-0 CAPLUS

CN 9(10H)-Anthracenone, 1,8-dihydroxy- (CA INDEX NAME)

RN 1210-12-4 CAPLUS

CN 9-Anthracenecarbonitrile (CA INDEX NAME)

RN 18004-57-4 CAPLUS

CN 9-Anthracenecarboxaldehyde, oxime (CA INDEX NAME)

RN 53531-31-0 CAPLUS

CN Ethanone, 1-(9-anthracenyl)-2,2,2-trifluoro- (CA INDEX NAME)

IT 1468-95-7, 9-Anthracenemethanol

RL: RCT (Reactant); RACT (Reactant or reagent)
(coating binder monomer precursor and chromophore additive;
acrylic antireflective coatings for use in microlithog. in fabrication
of semiconductor devices)

RN 1468-95-7 CAPLUS

CN 9-Anthracenemethanol (CA INDEX NAME)

IT 31645-34-8P, 9-Anthrylmethyl acrylate

RL: IMF (Industrial manufacture); RCT (Reactant); PREP (Preparation); RACT (Reactant or reagent)

(coating binder monomer; acrylic antireflective coatings for

use in microlithog. in fabrication of semiconductor devices)

RN 31645-34-8 CAPLUS

CN 2-Propenoic acid, 9-anthracenylmethyl ester (CA INDEX NAME)

L5 ANSWER 18 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER:

1999:327012 CAPLUS

DOCUMENT NUMBER:

130:359300

TITLE:

Antireflective coating composition containing photoacid generator, substrate having its coating layer, and manufacture of photoresist relief image

using it

INVENTOR(S):

Pavelchek, Edward K.; Docanto, Manuel

PATENT ASSIGNEE(S): SOURCE:

Shipley Company L.L.C., USA Jpn. Kokai Tokkyo Koho, 55 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT: 2

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 11133618	Α	19990521	JP 1998-61845	19980206
JP 3408415	B2	20030519		
US 5939236	Α	19990817	US 1997-797741	19970207
PRIORITY APPLN. INFO.:			US 1997-797741 A	19970207

AB The composition for use with overcoated photoresists comprises (A) a resin binder, (B) an acid or thermal acid generator, and (C) a photoacid generator. The substrate is successively coated with the above composition layer and a photoresist layer. The photoresist relief image is manufactured by (1) successively applying the above composition and a photoresist composition on a

substrate, (2) exposing the photoresist layer to activating radiation to generate acids from the photoacid generator, and (3) developing the exposed photoresist layer. The coating composition, particularly useful for deep UV applications in patterning semiconductor wafers, reduces undesired footing of overcoated resist relief images.

IT 161065-83-4P

RL: PNU (Preparation, unclassified); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses)

(antireflective coating composition containing photoacid generator used with overcoated photoresists for high-resolution resist reliefs without footing) ${}^{\circ}$

RN 161065-83-4 CAPLUS

CN 2-Propenoic acid, 2-methyl-, 9-anthracenylmethyl ester, polymer with 2-hydroxyethyl 2-methyl-2-propenoate (CA INDEX NAME)

CM 1

868-77-9 CRN CMF C6 H10 O3

L5 ANSWER 19 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER:

1989:644203 CAPLUS

DOCUMENT NUMBER:

111:244203

ORIGINAL REFERENCE NO.:

111:40347a,40350a

TITLE:

Electrophotographic printing plate containing

naphthalocyanine or anthracyanine sensitizer

INVENTOR(S):

Miyazaki, Shiyuji; Sakamoto, Mare; Suda, Yasumasa Toyo Ink Mfg. Co., Ltd., Japan

PATENT ASSIGNEE(S):

Jpn. Kokai Tokkyo Koho, 10 pp.

SOURCE:

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese 1

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 01032270	Α	19890202	JP 1987-188524	19870728
PRIORITY APPLN. INFO.:			JP 1987-188524	19870728
GI				

Ι

AΒ In the title printing plate, a photoconductive layer contains a photoconductive Zn oxide, a binder resin, and ≥ 1 I [A1-A4 = naphthalene ring, or anthracene ring; M = Group IA, IB, IIA, IIB, IIIA, IIIB, IVA, IVB, VB, VIB, VIIB, or VIII metal atom; Z = halo, O, OH, OR1, OSiR2R3R4; R1 = alkyl, aryl, acyl, cycloalkyl, polyether; R2, R3, R4 = alkyl, aryl, cycloalkyl, siloxyl, alkoxy; X = halo, OH, alkyl, aryl, heterocyclyl, OR5, SR5, NR6R7, SO2NR8R9, CH2NHCOCH2NR8R9, COOR9, NO2, SO3H, CN; R5 = R1; R6, R7 = H, alkyl, cycloalkyl, aryl; R6 and R7 may form a N-containing 4-7-membered heterocyclic ring; R8 = H, alkyl; R9 = H, alkyl, aryl, heterocyclyl, R10NR11R12; R10-R12 = alkyl; R11 and R12 may form a N, O, or S-containing heterocyclic ring; p = 0-2; k, l, m, n = 0-8]. The printing plate is sensitive to a semiconductor laser.

IT 40925-31-3

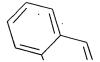
CN

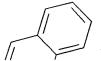
RL: DEV (Device component use); USES (Uses)
(electrophotog. printing plate containing, as sensitizer)

RN 40925-31-3 CAPLUS

Copper, [37H,39H-tetranaphtho[2,3-b:2',3'-g:2'',3''-1:2''',3'''-q]porphyrazinato(2-)-N37,N38,N39,N40]-, (SP-4-1)- (9CI) (CA INDEX NAME)

PAGE 1-A





ANSWER 20 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER:

1989:85352 CAPLUS

DOCUMENT NUMBER:

110:85352

ORIGINAL REFERENCE NO.: 110:13951a,13954a

TITLE:

Laminated electrophotographic photoreceptor with

charge transporting layer containing

tetramethylbenzene

INVENTOR(S):

Yasumori, Akiyoshi; Enomoto, Takamichi; Kato, Tatsuya

PATENT ASSIGNEE(S):

Ricoh Co., Ltd., Japan

SOURCE:

Jpn. Tokkyo Koho, 4 pp.

DOCUMENT TYPE:

CODEN: JAXXAD Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

	PATENT NO.	KIND	DATE	APPLICATION NO.		DATE
	JP 63026379	В	19880530	JP 1978-68096	,	19780606
	JP 54158928	Α	19791215			
PRIC	RITY APPLN. INFO.:			JP 1978-68096	A	19780606
AB	In a composite-type	e elect:	cophotog. pho	otoreceptor in which a	L	
	charge-generating 1	layer co	omprising a	p-type semiconductor a	ınd	a
	resin binder and a	charge-	transportine	g layer comprising an		
	electron donor and	a resin	n binder are	successively deposite	:d	on
	a conductive suppor	t, tet:	ramethylbenz	ene is incorporated in	ı ti	he charge
	transporting layer.	The p	photorecepto	r shows good initial e	:le	ctrostatic
	characteristic and	good di	irability.			
ΙT	71530-63-7	_	_			

RL: USES (Uses)

(electrophotog. photoreceptor charge-transporting layer containing)

71530-63-7 CAPLUS RN

Benzenamine, 4-[2-(9-anthracenyl)ethenyl]-N, N-diethyl- (CA INDEX NAME) CN

L5 ANSWER 21 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER: 1984:129860 CAPLUS

DOCUMENT NUMBER: 100:129860

ORIGINAL REFERENCE NO.: 100:19660h,19661a

TITLE: Electrophotographic photosensitive material

PATENT ASSIGNEE(S): Fujitsu Ltd., Japan

SOURCE: Jpn. Kokai Tokkyo Koho, 5 pp.

CODEN: JKXXAF

DOCUMENT TYPE: Patent LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 58181053	Α	19831022	JP 1982-63379	19820416
PRIORITY APPLN. INFO.:			JP 1982-63379	19820416

$$Z$$
 $CH = CH) 3 - CH$
 Et
 R

AB The electrophotog. material has a supported layer containing (1) a photoconductive composition prepared by treating a photoconductive material with

a sensitizing dye and a 1st charge-transfer compound in that order, (2) a 2nd charge-transfer compound, and (3) a resin. Compound I (Z = S, C, R = I, Br) is an example of a preferable sensitizing dye, and phthalocyanine is an example of the photoconductive material. This composition provides high sensitivity and high charge voltage in spite of using the relatively insensitive Cu phthalocyanine-binder system. Thus, Cu phthalocyanine (Lionol Blue SM, Dainippon Ink & Chemical) was treated with 1,1'-diethyl-11-bromo-4,4'-quinodicarbocyanine bromide (NK-1950, Japanese Inst. for Photosensitizing Dyes, Co.) in a dispersion in MeOH, separated and again similarly treated in benzene/iso-PrOH solvent with 2,5-bis(4'-diethylaminophenyl)-1,3,4-oxadiazole. The treated Cu phthalocyanine 10 was mixed with poly(N-vinylcarbazole) 2 and polyester resin (Polyester Adhesive 49,000, Du Pont) 16 in THF to obtain a coating solution Photosensitive material using this composition was chargeable to 1.5

times higher voltage compared to a material using untreated Cu phthalocyanine and was sensitive to ≥900 nm light including semiconductor laser light.

29659-51-6 IT

RL: USES (Uses)

(electrophotog. photoconductive composition containing cyanine dye- and charge

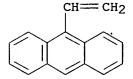
transfer compound-treated copper phthalocyanine and)

29659-51-6 CAPLUS RN

Anthracene, 9-ethenyl-, homopolymer (9CI) (CA INDEX NAME) CN

CM

CRN 2444-68-0 CMF C16 H12



ANSWER 22 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER: 1983:566984 CAPLUS

DOCUMENT NUMBER:

99:166984

ORIGINAL REFERENCE NO.: 99:25477a,25480a

Electrophotographic photosensitive materials

APPLICATION NO.

PATENT ASSIGNEE(S):

Canon K. K., Japan

spectral sensitivity, and good moisture and heat resistances.

SOURCE:

Jpn. Kokai Tokkyo Koho, 3 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent

LANGUAGE:

Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

			•
PATENT	NO.	KIND	DATE

	JP 57136655	A 1982	0823 JP	1981-23342	19810219	
PRIC	RITY APPLN. INFO.:			1981-23342	19810219	
AB	Electrophotog. plate	s are descr	ibed which	have a photoco	nductor layer	
	composed of amorphou	s Si, a cha	lcogen type	e inorg. photoc	onductor, and a	
	thermoplastic acryli	c resin bin	der, and a	2nd photocondu	ctor	
	layer from an organi	c semicondu	ctor. The	electrophotog.	plates	
	exhibit good spectra	l sensitivi	ty and good	d heat resistan	ce. Thus, an Al	
	cylinder was coated					40,
	and an acrylic resin					
	coated with a poly(v					
	shrinkable polyester					

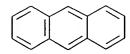
IT 120-12-7, uses and miscellaneous

RL: USES (Uses)

(electrophotog. plate with photoconductor layer containing amorphous silicon, chalcogen and)

RN 120-12-7 CAPLUS

Anthracene (CA INDEX NAME) CN



ANSWER 23 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER: 1980:613348 CAPLUS

DOCUMENT NUMBER: 93:213348

ORIGINAL REFERENCE NO.: 93:33919a,33922a

TITLE:

LANGUAGE:

Multilayer electrophotographic plates

Ricoh Co., Ltd., Japan PATENT ASSIGNEE(S):

SOURCE:

Jpn. Kokai Tokkyo Koho, 4 pp.

CODEN: JKXXAF

DOCUMENT TYPE:

Patent Japanese

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

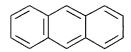
	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
	JP 55060955	Α	19800508	JP 1978-134117	19781031
PRIC	RITY APPLN. INFO.:			JP 1978-134117 A	19781031
AB	A multilayer electr	ophotog	. plate is c	composed of (1) a conduc	ctor support;
	(2) an N-type charg	e trans	fer layer wh	ose main constituent is	an electron
	acceptor; (3) a N-t	ype cha	rge generati	ng layer made of ZnO, k	oinder
	, and a sensitizer;	(4) a	P-type charg	e generating layer made	e of a P-type
	semiconductor, and	(5) a P	-type charge	-transfer layer whose m	nain
	constituent is an e	lectron	donor. The	order of the above lay	er may be
	reversed. Thus, an	Al lam	uinated polye	ster film support was o	coated with
	(1) a tetranitroflu	oroenon	e-polystyren	e layer, (2) a ZnO-base	ed composition
•	layer containing ac	rylic r	esin, Rose B	engal, and Tetrabromoph	nenol Blue, (3) an
	amorphous Se layer,	and (4) a poly(vin	ylcarboazole) layer to	give an
	electrophotog. plat	e with	excellent pa	nchromatic sensitivity.	
T m	75420 11 7			-	

IT75429-11-7

> RL: DEV (Device component use); USES (Uses) (multilayer electrophotog. plate containing)

RN 75429-11-7 CAPLUS

Anthracene, (2-phenylethenyl) - (9CI) (CA INDEX NAME) CN



D1-CH=CH-Ph

ANSWER 24 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER:

1979:620313 CAPLUS

DOCUMENT NUMBER:

91:220313

ORIGINAL REFERENCE NO.:

91:35359a,35362a

TITLE: INVENTOR(S): Development of charged images Takasu, Yoshio; Hino, Takashi

PATENT ASSIGNEE(S):

Canon K. K., Japan

SOURCE:

Ger. Offen., 35 pp.

CODEN: GWXXBX

DOCUMENT TYPE:

Patent

LANGUAGE:

German

FAMILY ACC. NUM. COUNT: 1 PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.		DATE
DE 2854825	A1	19790628	DE 1978-2854825		19781219
DE 2854825	C2	19881117			_+
JP 54086335	Α	19790709	JP 1977-154630		19771222
JP 63025337	В	19880525			
US 4258116	Α	19810324	US 1978-968205		19781211
PRIORITY APPLN. INFO.:			JP 1977-154630	Α	19771222
			JP 1977-154631	Α	19771222

AB Developer compns. for use in electrog. or electrophotog. consist of fine toner particles containing an organic semiconductor (≥0.1 weight parts/100 weight parts binder resin) which are supported on a dispenser surface of a metal or inorg. semiconductor and which in an elec. field take on a carrier-injection-induced charge of opposite polarity to that of the charge images 5 μ to 5 mm away from the dispenser surface. Thus, a toner of 11.5-μ particles of poly(9-vinylcarbazole) 10, polystyrene 40, magnetite 20, and carbon black 1 weight part dispensed from a rotating magnetized drum coated with Cu2O on Al and set at 120-μ from the charge-image drum with ZnO paper gave on application of an elec. field images with Dmax 1.20 and fog d. 0.05 after 1 copy and 1.19 and 0.05 after 100 copies as compared to 0.20 and 0.08 for 1 copy and 0.22 and 0.09 for 100 copies, resp., for a toner of 20-μ particles of polystyrene 100 and magnetite 40 weight parts.

IT 37372-26-2

RL: USES (Uses)

(toners containing, for electrostatog. developers)

RN 37372-26-2 CAPLUS

CN Anthracene, ethenyl-, homopolymer (CA INDEX NAME)

CM 1

CRN 30521-30-3 CMF C16 H12 CCI IDS

 $D1-CH=CH_2$

L5 ANSWER 25 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER: 1972:128986 CAPLUS

DOCUMENT NUMBER: 76:128986

ORIGINAL REFERENCE NO.: 76:20879a,20882a

TITLE: Semiconductor compounds for coating

substrates

INVENTOR(S): Perez-Albuerne, Evelio A.

PATENT ASSIGNEE(S): Eastman Kodak Co. SOURCE: Fr. Demande, 22 pp.

CODEN: FRXXBL

DOCUMENT TYPE: Patent LANGUAGE: French

FAMILY ACC. NUM. COUNT: 5

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
FR 2058353	A 5	19710528	FR 1970-30230	19700818
FR 2058353	B1	19760903		•
US 3634336	Α	19720111	US 1969-851088	19690818
PRIORITY APPLN. INFO.:			US 1969-851088 A	19690818

AB Polymeric substrates are coated with semiconductor compds. which are organic complexes comprising electron donors derived from polynuclear aromatic hydrocarbons having at least 2 atoms joined by a bridge containing 2-4 atoms of an element of Group VIb, such as S, Se, and Te, and electron acceptors which are either mineral or organic Thus, a complex based on tetrathiotetracene (I) [193-44-2] was used. Aqueous I acetate containing about 10 mg/l. and 5 mg/l. gelatin were applied to a polyester surface. The film was then dried in a hot-air stream to give the semiconductor surface.

IT 193-44-2D, Naphthaceno[5,6-cd:11,12-c'd']bis[1,2]dithiole,
 complexes with polystyrene sulfone 35201-34-4 36015-72-2
 36452-11-6 36519-97-8 36529-19-8

RL: TEM (Technical or engineered material use); USES (Uses) (coatings, semiconducting)

RN 193-44-2 CAPLUS

CN Naphthaceno[5,6-cd:11,12-c'd']bis[1,2]dithiole (CA INDEX NAME)

RN 35201-34-4 CAPLUS

CN 1,2-Benzenedicarboxylic acid, compd. with naphthaceno[5,6-cd:11,12-c'd']bis[1,2]dithiole (9CI) (CA INDEX NAME)

CM 1

CRN 193-44-2 CMF C18 H8 S4

CM 2

CRN 88-99-3 CMF C8 H6 O4

RN 36015-72-2 CAPLUS

CN 2-Butenedioic acid (2Z)-, compd. with naphthaceno[5,6-cd:11,12-c'd']bis[1,2]dithiole (9CI) (CA INDEX NAME)

CM 1

CRN 193-44-2 CMF C18 H8 S4

CM 2

CRN 110-16-7 CMF C4 H4 O4

Double bond geometry as shown.

RN 36452-11-6 CAPLUS

CN Naphthaceno[5,6-cd:11,12-c'd']bis[1,2]dithiole, compd. with iodine (1:1) (9CI) (CA INDEX NAME)

CM 1

CRN 7553-56-2

CMF I2

I-I

CM 2

CRN 193-44-2 CMF C18 H8 S4

RN 36519-97-8 CAPLUS

CN Naphthaceno[5,6-cd:11,12-c'd']bis[1,2]dithiole, radical ion(1+), bromide (9CI) (CA INDEX NAME)

• Br-

RN 36529-19-8 CAPLUS

CN Acetic acid, compd. with naphthaceno[5,6-cd:11,12-c'd']bis[1,2]dithiole (9CI) (CA INDEX NAME)

CM 1

CRN 193-44-2 CMF C18 H8 S4

CM 2

CRN 64-19-7 CMF C2 H4 O2

L5 ANSWER 26 OF 26 CAPLUS COPYRIGHT 2008 ACS on STN

ACCESSION NUMBER:

1965:19667 CAPLUS

DOCUMENT NUMBER:

62:19667

ORIGINAL REFERENCE NO.: 62:3522e-f

TITLE: Optically sensitized photoresistors

INVENTOR(S): Weisbeck, Roland; Brockes, Andreas; Nassenstein,

Heinrich

PATENT ASSIGNEE(S): Farbenfabriken Bayer A.-G.

SOURCE:
DOCUMENT TYPE:

LANGUAGE:

4 pp.
Patent
Unavailable

FAMILY ACC. NUM. COUNT:

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
DE 1180859		19641105	DE 1962-F38227	19621106
BE 638530			BE	
RTTY APPLN. TNFO. :			DE.	19621106

AB The spectral sensitivity of a photoresistor is extended toward shorter

wavelengths by coating it with diisobutyl 3,9-perylenedicarboxylate (I) or 9,10-dianilinoanthracene (fluorescent compds. which emit radiation in the sensitivity range of the photoconductor) as a 0.1-1% dispersion in a transparent binder which as light conductor establishes the optical contact between the semiconductor and the fluorescent particles. In an example, the spectral sensitivity maximum of a CdS photoresistor is shifted from 605 to 590 mm by a 40-mm coating of a 0.2% dispersion of I in a colorless epoxy resin.

IT 2233-88-7, 9,10-Anthracenediamine, N,N'-diphenyl-

(spectral sensitivity increase of CdS photo-resistors by)

RN 2233-88-7 CAPLUS

CN 9,10-Anthracenediamine, N9,N10-diphenyl- (CA INDEX NAME)

=>

---Logging off of STN---

=>

Executing the logoff script...

=> LOG Y

COST IN U.S. DOLLARS	SINCE FILE	TOTAL
	ENTRY	SESSION
FULL ESTIMATED COST	147.86	327.10
DISCOUNT AMOUNTS (FOR QUALIFYING ACCOUNTS)	SINCE FILE	TOTAL
	ENTRY	SESSION
CA SUBSCRIBER PRICE	-20.80	-20.80